## NSN 5961-01-305-4854

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-305-4854 **Inclosure Material:** Ceramic **Overall Length:** 0.300 inches **Overall Height:** 0.095 inches **Overall Width:** 1.000 inches **End Application:** Pacer special **Component Name And Quantity:** 7 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 75.0 reverse breakdown voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 500.00 milliamperes forward current, average preset all semiconductor device diode **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 88818-a531a152 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 14 pin **Specification Data:** 81349-mil-prf-19500/474 government specification Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.